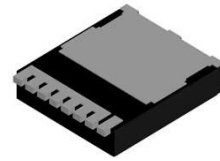


FEATURES

- Drain-Source Withstand Voltage: 100V
- Max. $R_{DS(on)}$: 1.5m Ω @ $V_{GS}=10V$
- Automotive applications
- AEC-Q101 Qualified
- Excellent ON resistance
- Package TOLL-8L
- 100% Rg and Avalanche tested
- MSL1

PRODUCT APPEARANCE

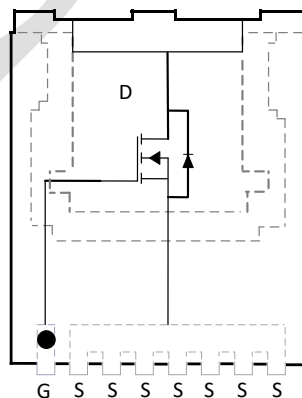
TOLL-8L

DESCRIPTION

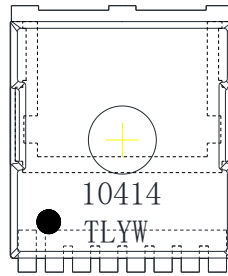
The SNM101R5TLAQ is N-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. This device is suitable for use in high performance automotive DC-DC conversion, power switch and charging circuit. Standard Product SNM101R5TLAQ is in compliance with RoHS.

Applications:

- Automotive systems
- DC/DC converters
- Power supply converters circuit
- Load/Power Switching for portable device

PIN CONFIGURATION

Top view

MARKING


10414 = Device Code
 TL = Special Code
 Y = Year
 W = Week

LIMITING VALUES

Parameter	Symbol	Condition	Value	Unit
Drain-Source Voltage	V_{DS}		100	V
Gate-Source Voltage	V_{GS}		± 20	V
Continuous Drain Current	I_D	$T_C=25^\circ\text{C}$	366	A
		$T_C=100^\circ\text{C}$	259	A
Pulsed Drain Current ⁽³⁾	I_{DM}		1220	A
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	73	A
		$T_A=100^\circ\text{C}$	61	A
Avalanche Energy $L=0.3\text{mH}$	E_{AS}		500	mJ
Power Dissipation ⁽²⁾	P_D	$T_C=25^\circ\text{C}$	429	W
		$T_C=100^\circ\text{C}$	214	W
Power Dissipation ⁽¹⁾	P_D	$T_A=25^\circ\text{C}$	17.1	W
		$T_A=100^\circ\text{C}$	12.0	W
Operating Junction Temperature	T_J		-55 to 175	$^\circ\text{C}$
Storage Temperature Range	T_{STG}		-55 to 175	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

Single Operation					
Parameter		Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance ⁽¹⁾	Steady State	$R_{\theta JA}$	29	38	°C/W
Junction-to-Case Thermal Resistance ⁽²⁾	Steady State	$R_{\theta JC}$	0.24	0.35	

ELECTRONICS CHARACTERISTICS

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$, $I_D = 250\mu A$	100			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	BV_{DSS}/T_J			56		mV/°C
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=100V$, $V_{GS}=0V$, $T_J=25^\circ C$			10	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS}=0V$, $V_{GS}=20V$			100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}$, $I_D = 250\mu A$	2.5	3.0	3.5	V
Threshold Temperature Coefficient	$V_{GS(TH)}/T_J$			-8.3		mV/°C
Drain-to-source On-resistance ⁽⁴⁾	$R_{DS(on)}$	$V_{GS} = 10V$, $I_D = 100A$		1.25	1.5	m Ω
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance ⁽⁵⁾	C_{ISS}	$V_{GS} = 0V$, $f = 1.0MHz$, $V_{DS}=50V$		12250		pF
Output Capacitance ⁽⁵⁾	C_{OSS}			2810		
Reverse Transfer Capacitance ⁽⁵⁾	C_{RSS}			62		
Total Gate Charge ⁽⁵⁾	$Q_{G(TOT)}$	$V_{GS}=10V$, $V_{DS}=50V$, $I_D = 100A$		190		nC
Gate-to-Source Charge ⁽⁵⁾	Q_{GS}			49		
Gate-to-Drain Charge ⁽⁵⁾	Q_{GD}			47		
Gate Resistance	R_g	$f=1MHz$		1.7		Ω
SWITCHING CHARACTERISTICS ⁽⁵⁾						

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	td(ON)	V _{GS} =10V, V _{DS} = 50V, I _D =100A, R _G =6Ω		25		ns
Rise Time	tr			94		
Turn-Off Delay Time	td(OFF)			98		
Fall Time	tf			66		
Body Diode Reverse Recovery Time	trr	I _F =20A, dI/dt=100A/μs		170		ns
Body Diode Reverse Recovery Charge	Q _{rr}	I _F =20A, dI/dt=100A/μs		280		nC
BODY DIODE CHARACTERISTICS						
Forward Voltage ⁽⁴⁾	V _{SD}	V _{GS} =0 V, I _S =100A	0.5	0.7	1.2	V

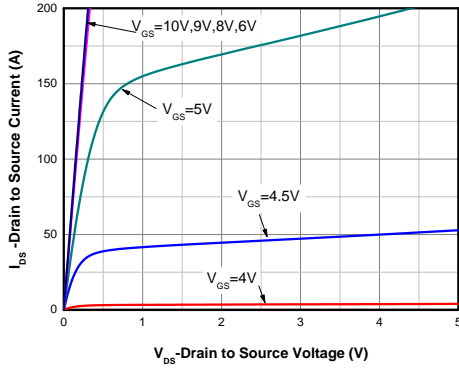
(T_J=25°C, unless otherwise noted.)

Note:

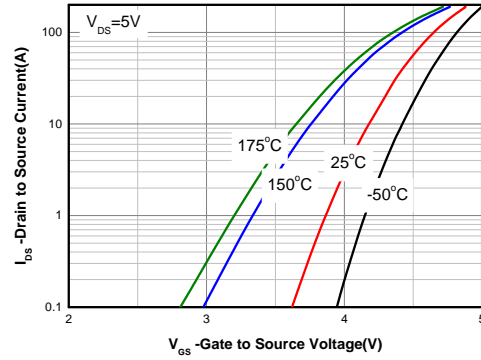
- (1) FR-4 board (38mm × 38mm × t1.6mm, 70μm Copper) partially covered with copper (645mm² area). The power dissipation P_{DSM} is based on Junction-to-Ambient thermal resistance value and the T_{J(MAX)}=175°C. The value is only for reference, any application depends on the user's specific board design.
- (2) The power dissipation P_D is based on T_{J(MAX)}=175°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.
- (3) Repetitive rating, pulsed, duty cycle ~1%, keep initial T_J =25°C, the maximum allowed junction temperature of 175°C.
- (4) The static characteristics are obtained using ~380μs pulses, duty cycle ~1%.
- (5) The parameter is not subject to production test – verified by design / characterization.

TYPICAL CHARACTERISTICS

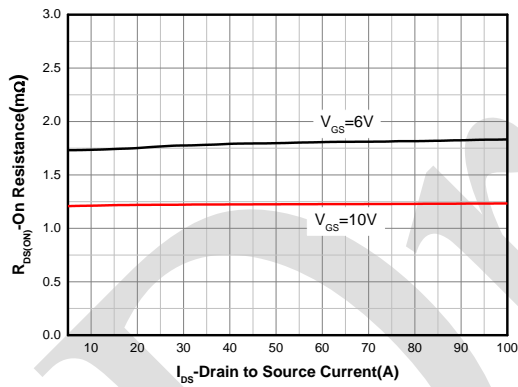
Ta=25°C, unless otherwise noted.



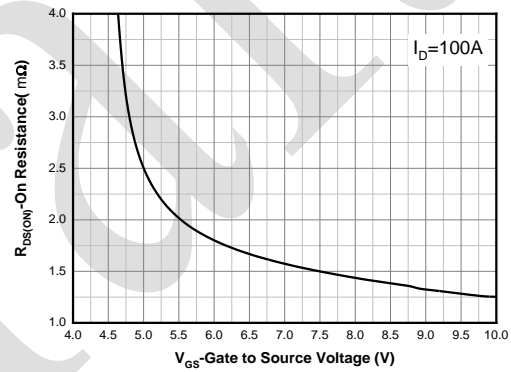
Output Characteristics ⁽⁴⁾



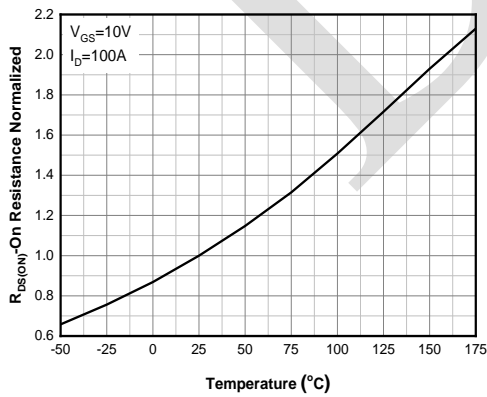
Transfer Characteristics ⁽⁴⁾



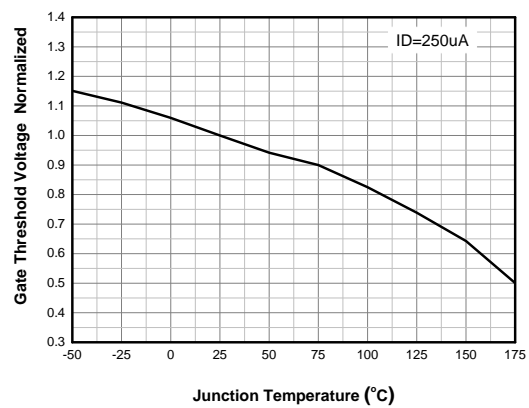
On-Resistance vs. Drain Current ⁽⁴⁾



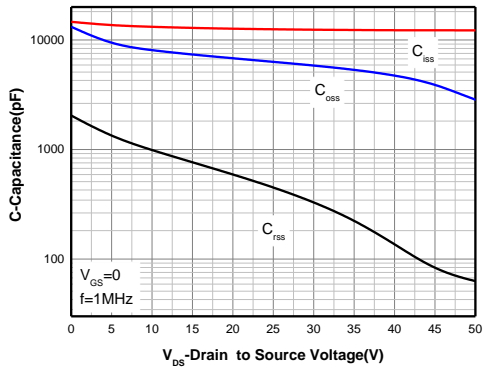
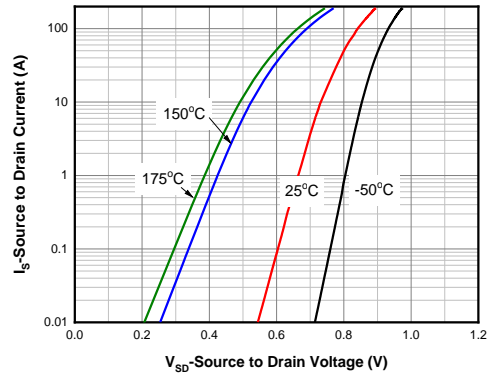
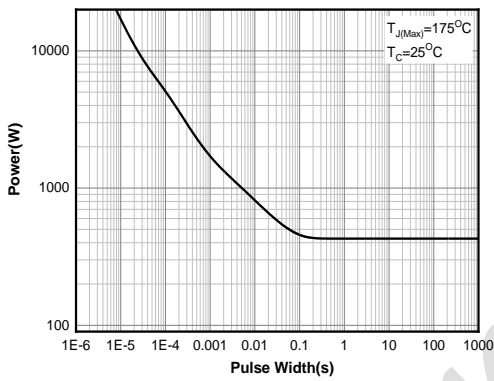
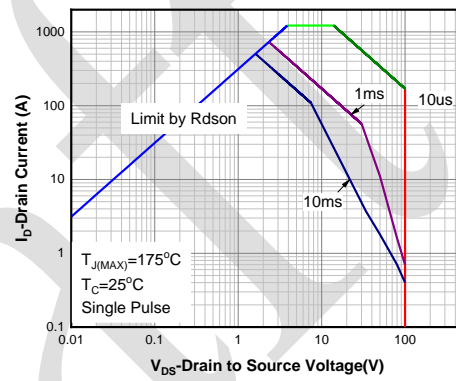
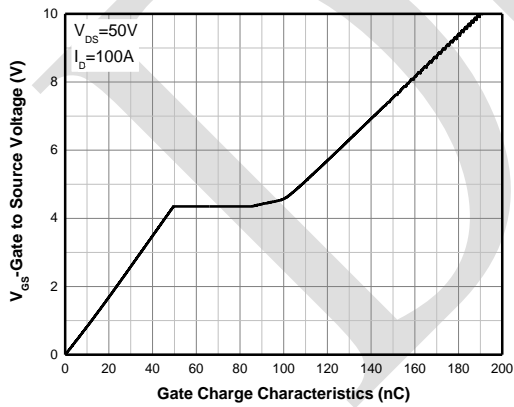
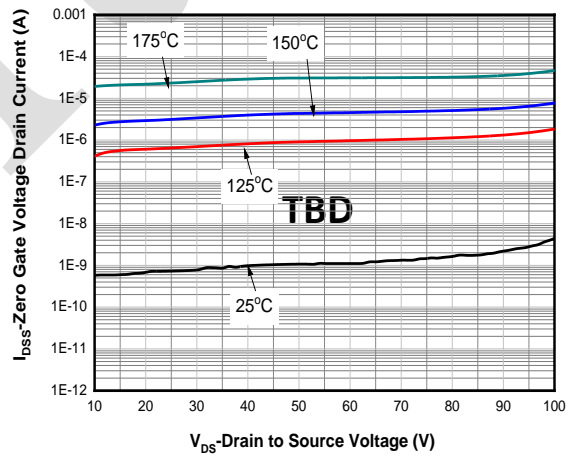
On-Resistance vs. Gate-to-Source Voltage ⁽⁴⁾

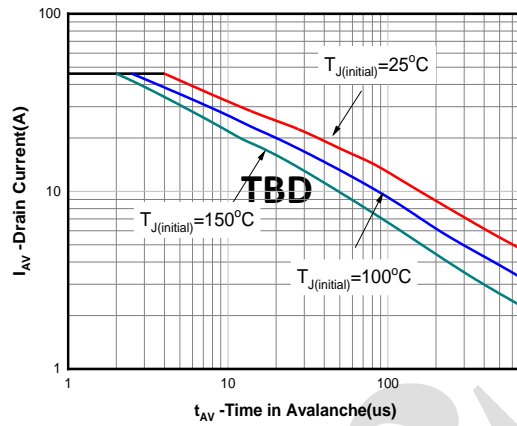
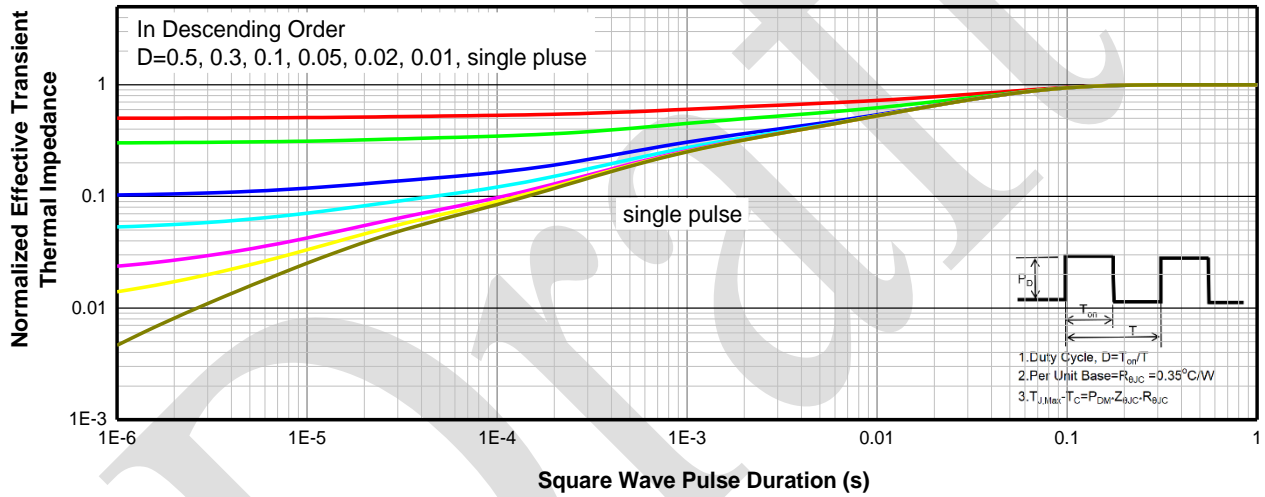
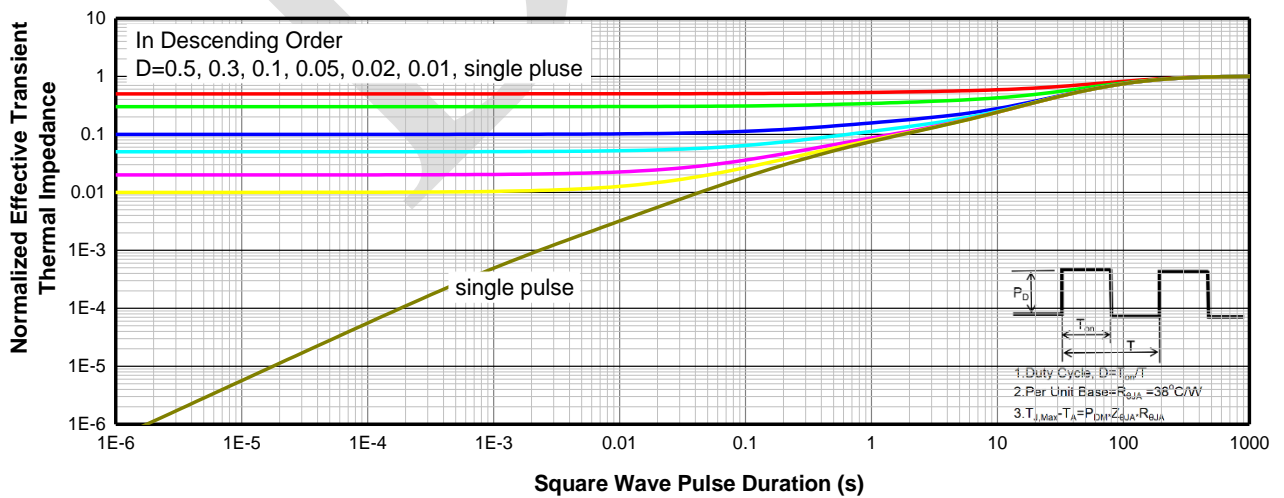


On-Resistance vs. Junction Temperature ⁽⁴⁾



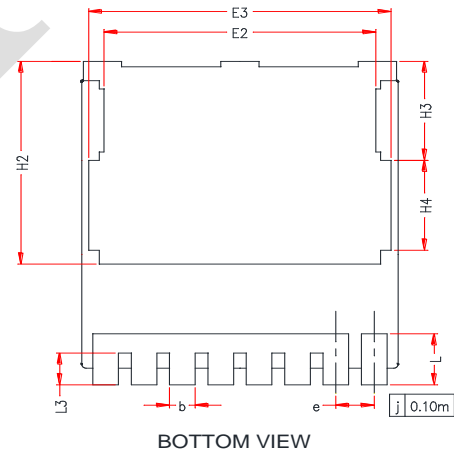
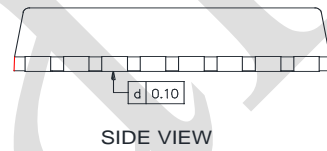
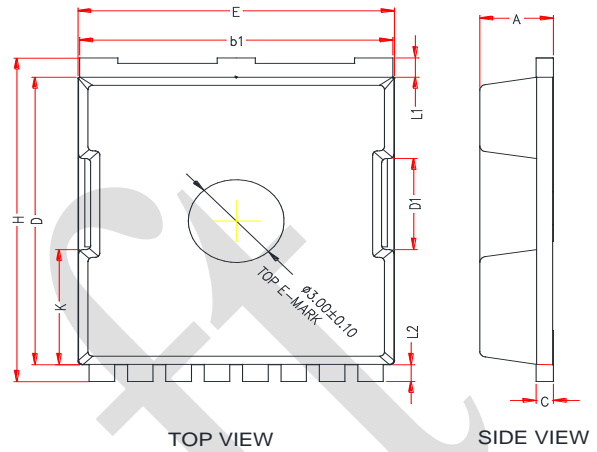
Threshold Voltage vs. Temperature

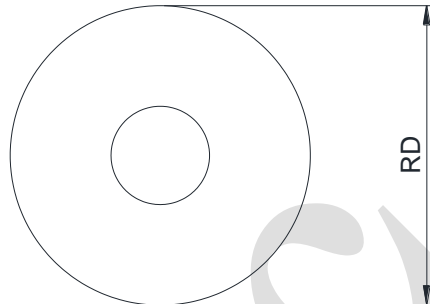
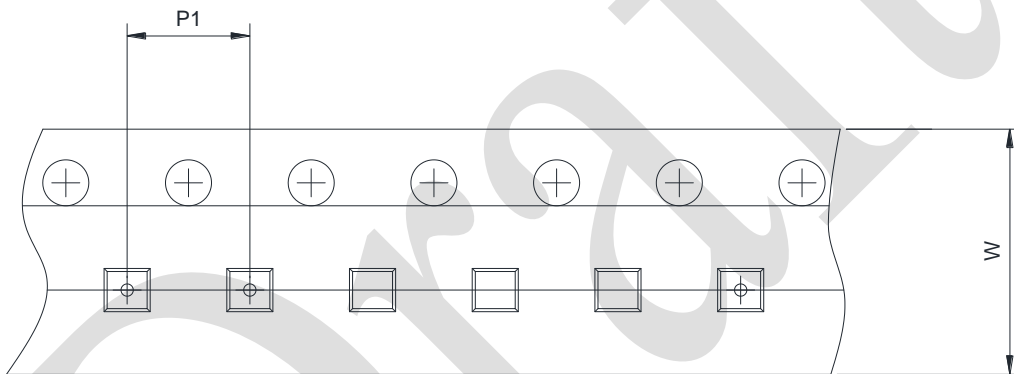
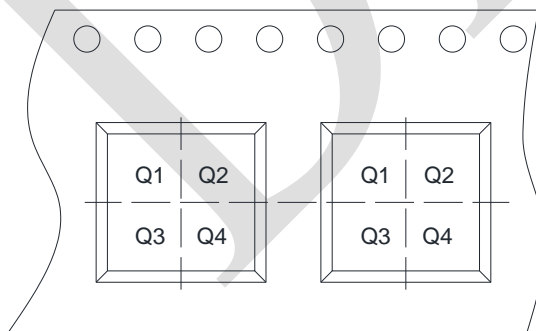

Capacitance

Body Diode Forward Voltage ⁽⁴⁾

Single Pulse power

Safe Operating Area

Gate Charge Characteristics

Drain Current vs. Drain Voltage


Avalanche characteristics

Transient Thermal Response (Junction-to-Case)

Transient Thermal Response (Junction-to-Ambient)

TOLL-8L DIMENSIONS
PACKAGE SIZE

Symbol	Min.	Typ.	Max.
A	2.20	2.30	2.40
b	0.70	0.80	0.90
b1	9.70	9.80	9.90
c	0.40	0.50	0.60
D	10.28	10.43	10.58
D1	3.15	3.30	3.45
E	9.70	9.90	10.10
E2	8.35	8.50	8.65
E3	9.31	9.46	9.61
e	1.10	1.20	1.30
H	11.48	11.73	11.88
H2	7.20	7.35	7.50
H3	3.44	3.59	3.74
H4	3.11	3.26	3.41
K	4.03	4.18	4.33
L	1.60	1.85	2.10
L1	0.55	0.70	0.85
L2	0.45	0.60	0.75
L3	1.00	1.15	1.30



TAPE AND REEL INFORMATION
Reel Dimensions

Tape Dimensions

Quadrant Assignments For PIN1 Orientation In Tape


User Direction of Feed

RD	Reel Dimension	<input type="checkbox"/> 7inch	<input checked="" type="checkbox"/> 13inch		
W	Overall width of the carrier tape	<input type="checkbox"/> 8mm	<input type="checkbox"/> 12mm	<input type="checkbox"/> 16mm	<input checked="" type="checkbox"/> 24mm
P1	Pitch between successive cavity centers	<input type="checkbox"/> 2mm	<input type="checkbox"/> 4mm	<input type="checkbox"/> 8mm	<input checked="" type="checkbox"/> 12mm
Pin1	Pin1 Quadrant	<input type="checkbox"/> Q1	<input checked="" type="checkbox"/> Q2	<input type="checkbox"/> Q3	<input type="checkbox"/> Q4

ORDERING INFORMATION

TYPE NUMBER	PACKAGE	PACKING
SNM101R5TLAQ-8/TR	TOLL-8L	Tape and reel

TOLL-8L is packed with 1800 pieces/disc in braided packaging.

Important statement

SIT reserves the right to change the above-mentioned information without prior notice.

REVISION HISTORY

Version number	Datasheet status	Revision date
V0.1	Draft version.	May 2024

Draft